ESD Protection Diode Array

Dual Common Anode

These dual monolithic silicon surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Specification Features:

- SOT-23 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Working Peak Reverse Voltage Range 5.0 V to 36 V
- Peak Power 300 Watt (8/20 μs)
- Low Leakage 1.0 μA
- Flammability Rating UL 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These are Pb–Free Devices

Mechanical Characteristics:

CASE: Void-Free, Transfer-Molded, Thermosetting Plastic Case FINISH: Corrosion Resistant Finish, Easily Solderable MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

Package Designed for Optimal Automated Board Assembly Small Package Size for High Density Applications Available in 8 mm Tape and Reel

Use the Device Number to Order the 7 Inch/3,000 Unit Reel Replace the "T1" with "T3" in the Device Number to Order the 13 Inch/10,000 Unit Reel

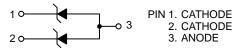


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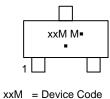
www.onsemi.com







MARKING DIAGRAM



xx = 05, 12, 15, 24, 36

= Date Code*

Μ

= Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]			
SM05T1G	SOT-23 (Pb-Free)	3,000/Tape & Reel			
SZSM05T1G	SOT-23 (Pb-Free)	3,000/Tape & Reel			
SM12T1G	SOT-23 (Pb-Free)	3,000/Tape & Reel			
SM15T1G	SOT-23 (Pb-Free)	3,000/Tape & Reel			
SM24T1G	SOT-23 (Pb-Free)	3,000/Tape & Reel			
SM36T1G	SOT-23 (Pb-Free)	3,000/Tape & Reel			

+For information on tape and reel specifications,

including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation @ 20 μs (Note 1) @ $T_L \leq 25^\circ C$	P _{pk}	300	W
IEC 61000–4–2 (ESD) Air Contact		±15 ±26	kV
IEC 61000-4-4 (EFT)		40	A
IEC 61000–4–5 (Lightning)		12	A
Total Power Dissipation on FR–5 Board (Note 2) @ T _A = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient	Ρ _D R _{θJA}	225 1.8 556	mW mW/°C °C/W
Total Power Dissipation on Alumina Substrate (Note 3) @ T _A = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient	Ρ _D R _{θJA}	300 2.4 417	mW mW/°C °C/W
Junction and Storage Temperature Range	T _J , T _{stg}	– 55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 3

2. $FR-5 = 1.0 \times 0.75 \times 0.62$ in.

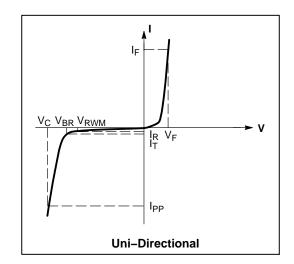
3. Alumina = 0.4 x 0.3 x 0.024 in., 99.5% alumina

NOTE: Other voltages may be available upon request

ELECTRICAL CHARACTERISTICS

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter				
I _{PP}	Maximum Reverse Peak Pulse Current				
V _C	Clamping Voltage @ IPP				
V _{RWM}	Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}				
V _{BR}	Breakdown Voltage @ I _T				
Ι _Τ	Test Current				
ΘV _{BR}	Maximum Temperature Coefficient of VBR				
١ _F	Forward Current				
V _F	Forward Voltage @ I _F				
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}				
I _{ZK}	Reverse Current				
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}				



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

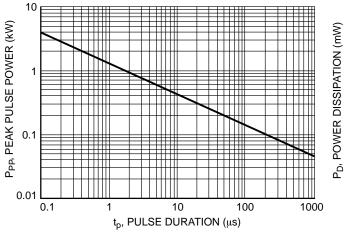
				V _{BR} , Breakdown Voltage			V _C @ I _{PP} =	Max I _{PP}	Typical Capacitance
		V _{RWM}	I _R @ V _{RWM}	(Volts)		ŀт	1 Amp	(Note 4)	(pF)
Device*	Device Marking	(Volts)	(μΑ)	Min	Max	mA	(Volts)	(Amps)	Pin 1 to 3 @ 0 Volts
SM05T1G	05M	5	10	6.2	7.3	1.0	9.8	17	225
SM12T1G	12M	12	1.0	13.3	15.75	1.0	19	12	95
SM15T1G	15M	15	1.0	16.7	19.6	1.0	24	10	100
SM24T1G	24M	24	1.0	26.7	31.35	1.0	43	5.0	60
SM36T1G	36M	36	1.0	40.0	46.95	1.0	60	4.0	45

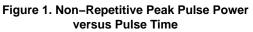
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. $8/20 \ \mu s$ pulse waveform per Figure 3

*Include SZ-prefix devices where applicable.







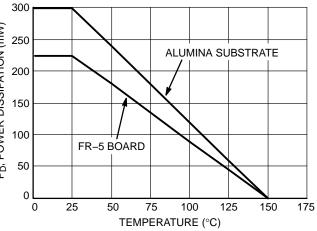


Figure 2. Steady State Power Derating Curve

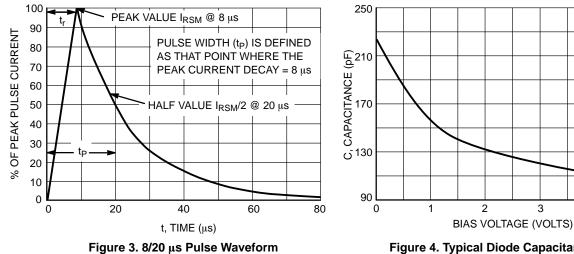


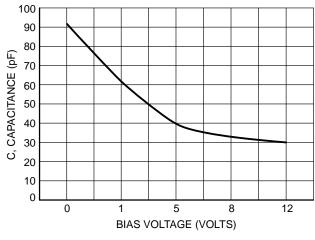
Figure 4. Typical Diode Capacitance (SM05)

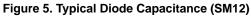
3

4

5

2





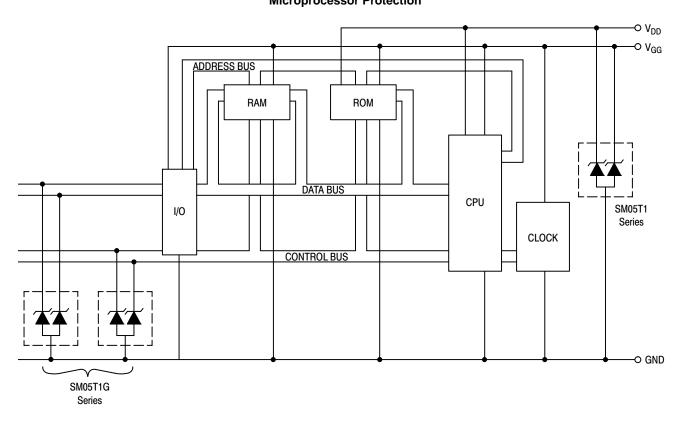
TYPICAL COMMON ANODE APPLICATIONS

Computer Interface Protection

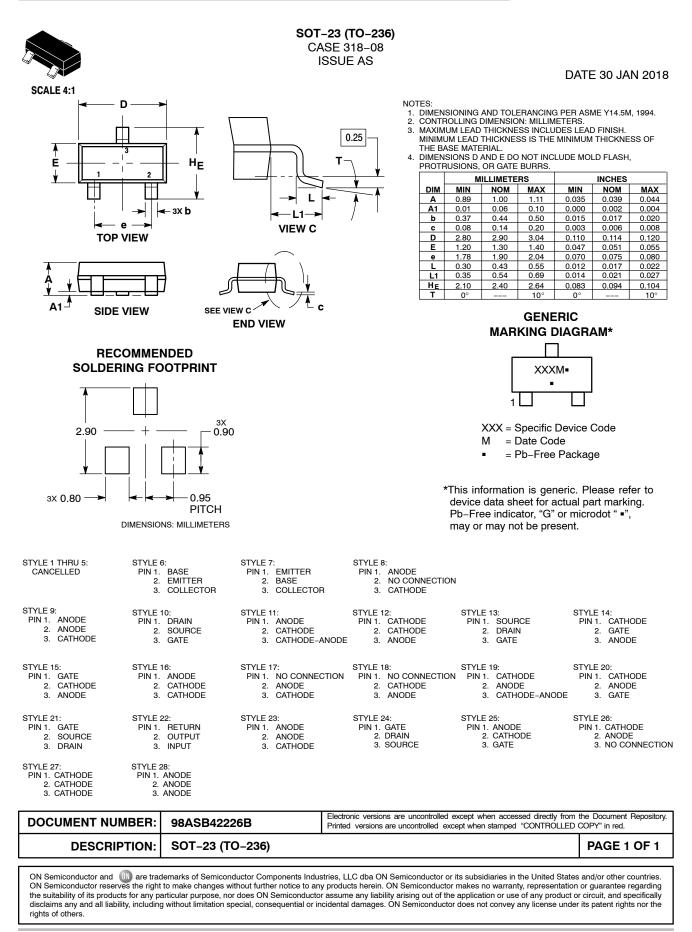
A quad junction common anode design in a SOT-23 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. Two simplified examples of surge protection applications are illustrated below.









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